Product Summary

BV_{DSS}	$R_{DS(ON)}$	I_D T_A = +25°C
30V	65mΩ @ V_{GS} = 10V	3.4A
	75mΩ @ V_{GS} = 4.5V	3.0A

Description and Applications

This new generation MOSFET is designed to minimize the on-state resistance ($R_{DS(ON)}$) yet maintain superior switching performance, making it ideal for high-efficiency power-management applications.

- Power-management functions
- Backlighting
- Load switches

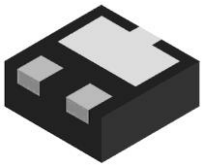
Features and Benefits

- Low On-Resistance
- Low Input/Output Leakage
- Fast Switching Speed
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative.**
  https://www.diodes.com/quality/product-definitions/

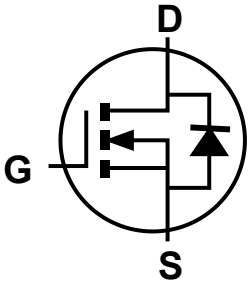
Mechanical Data

- Package: X2-DFN1010-3
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram
- Terminals: Finish — NiPdAu over Copper Leadframe. Solderable per MIL-STD-202, Method 208 e4
- Weight: 0.0015 grams (Approximate)

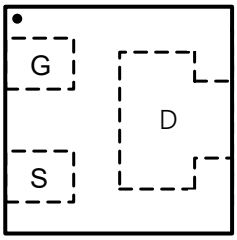
X2-DFN1010-3



Bottom View



Equivalent Circuit



Pin-Out Top View

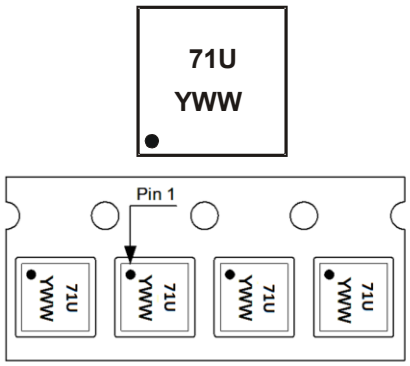
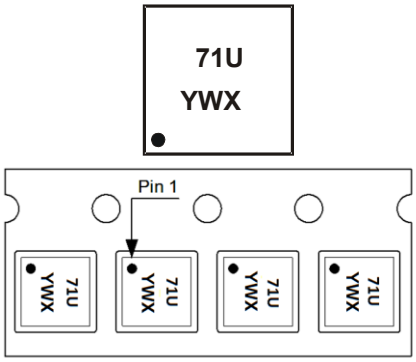
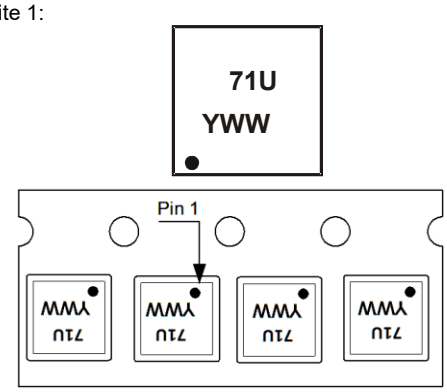
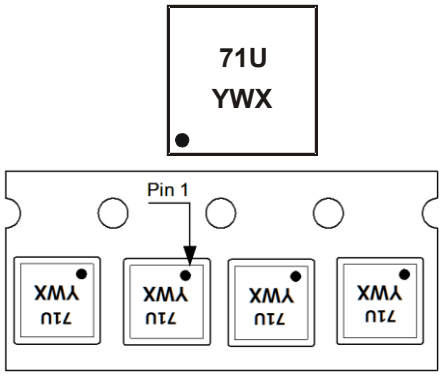
Ordering Information (Note 4)

Orderable Part Number	Package	Tape Width (mm)	Tape Pitch (mm)	Packing	
				Qty.	Carrier
DMN3071LFR4-7	X2-DFN1010-3	8	4	3000	Tape & Reel
DMN3071LFR4-7R	X2-DFN1010-3	8	4	3000	Tape & Reel

Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

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Marking Information

DMN3071LFR4-7	Site 1:  71U = Product Type Marking Code YWW = Date Code Marking Y = Year (ex: 6 = 2026) WW = Number of Week Site 2:  71U = Product Type Marking Code YWX = Date Code Marking Y = Year (ex: 6 = 2026) W = Week (ex: a = Week 27; z Represents Week 52 and 53) X = Internal Code (ex: U = Monday)
DMN3071LFR4-7R	Site 1:  71U = Product Type Marking Code YWW = Date Code Marking Y = Year (ex: 6 = 2026) WW = Number of Week Site 2:  71U = Product Type Marking Code YWX = Date Code Marking Y = Year (ex: 6 = 2026) W = Week (ex: a = Week 27; z Represents Week 52 and 53) X = Internal Code (ex: U = Monday)

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Marking Information (continued)

Site 1:

Date Code Key

Year	2018	-	2026	2027	2028	2029	2030	2031	2032	2033	2034	2035
Code	8	-	6	7	8	9	0	1	2	3	4	5

Site 2:

Date Code Key

Year	2018	-	2026	2027	2028	2029	2030	2031	2032	2033	2034	2035
Code	8	-	6	7	8	9	0	1	2	3	4	5

Week	1-26	27-52	53
Code	A-Z	a-z	z

Internal Code	Sun	Mon	Tue	Wed	Thu	Fri	Sat
Code	T	U	V	W	X	Y	Z

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Unit
Drain-Source Voltage			V_{DSS}	30	V
Gate-Source Voltage			V_{GSS}	±20	V
Continuous Drain Current (Note 6) V_{GS} = 10V	Steady State	T_A = +25°C T_A = +100°C	I_D	3.4 2.7	A
Maximum Continuous Body Diode Forward Current (Note 6)			I_S	1.5	A
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)			I_{DM}	15	A

Thermal Characteristics

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)		P_D	0.5	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	$R_{\theta JA}$	221	°C/W
Total Power Dissipation (Note 6)		P_D	1.1	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	$R_{\theta JA}$	107	°C/W
Operating and Storage Temperature Range		T_J, T_{STG}	-55 to +150	°C

Notes: 5. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
6. Device mounted on 1" x 1" FR-4 PCB with high coverage 2oz. copper, single sided.

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Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)						
Drain-Source Breakdown Voltage	BV_{DSS}	30	—	—	V	V_{GS} = 0, I_D = 250μA
Zero Gate Voltage Drain Current	I_{DSS}	—	—	1	μA	V_{DS} = 30V, V_{GS} = 0
Gate-Source Leakage	I_{GSS}	—	—	±100	nA	V_{GS} = ±20V, V_{DS} = 0
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	$V_{GS(TH)}$	1.0	—	2.5	V	V_{DS} = V_{GS}, I_D = 250μA
Static Drain-Source On-Resistance	$R_{DS(ON)}$	—	—	65 75	mΩ	V_{GS} = 10V, I_D = 3.2A V_{GS} = 4.5V, I_D = 3.2A
Diode Forward Voltage	V_{SD}	—	0.8	1.2	V	V_{GS} = 0, I_S = 1A
DYNAMIC CHARACTERISTICS (Note 8)						
Input Capacitance	C_{iss}	—	190	—	pF	V_{DS} = 15V, V_{GS} = 0 f = 1.0MHz
Output Capacitance	C_{oss}	—	36	—		
Reverse Transfer Capacitance	C_{rss}	—	26	—		
Gate Resistance	R_g	—	4.2	—	Ω	V_{DS} = 0, V_{GS} = 0, f = 1MHz
Total Gate Charge (V_{GS} = 4.5V)	Q_g	—	2.1	—	nC	V_{DS} = 15V, I_D = 4A
Total Gate Charge (V_{GS} = 10V)	Q_g	—	4.5	—		
Gate-Source Charge	Q_{gs}	—	0.5	—		
Gate-Drain Charge	Q_{gd}	—	0.8	—		
Turn-On Delay Time	$t_{D(ON)}$	—	1.7	—	ns	V_{DS} = 15V, V_{GS} = 10V, R_G = 3Ω, I_D = 4A
Turn-On Rise Time	t_R	—	5.7	—		
Turn-Off Delay Time	$t_{D(OFF)}$	—	6.0	—		
Turn-Off Fall Time	t_F	—	1.6	—		
Reverse-Recovery Time	t_{RR}	—	4.2	—	ns	I_F = 4A, di/dt = 100A/μs
Reverse-Recovery Charge	Q_{RR}	—	0.5	—	nC	

Notes: 7. Short duration pulse test used to minimize self-heating effect.
8. Guaranteed by design. Not subject to production testing.

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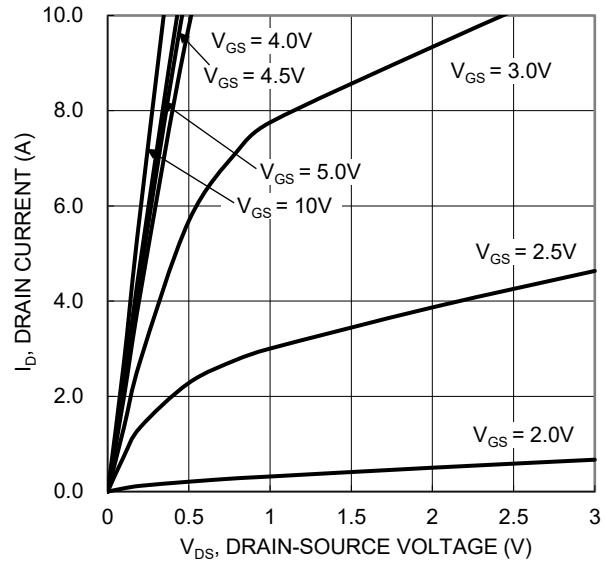


Figure 1. Typical Output Characteristic

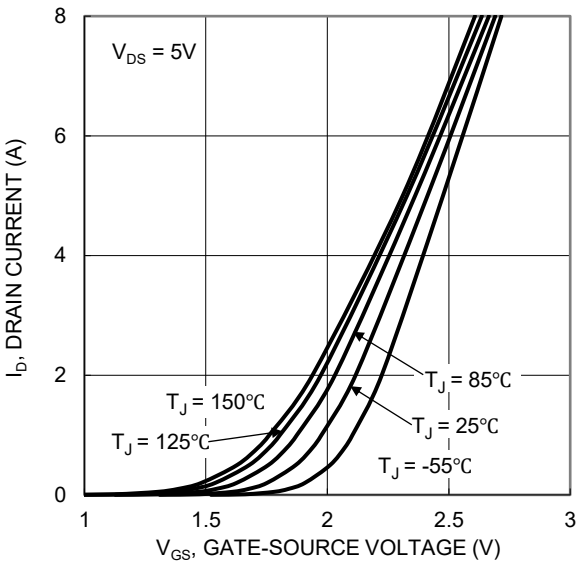


Figure 2. Typical Transfer Characteristic

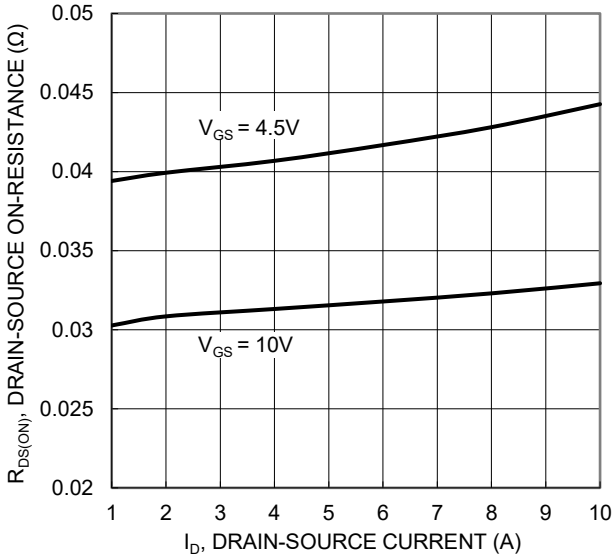


Figure 3. Typical On-Resistance vs. Drain Current and Gate Voltage

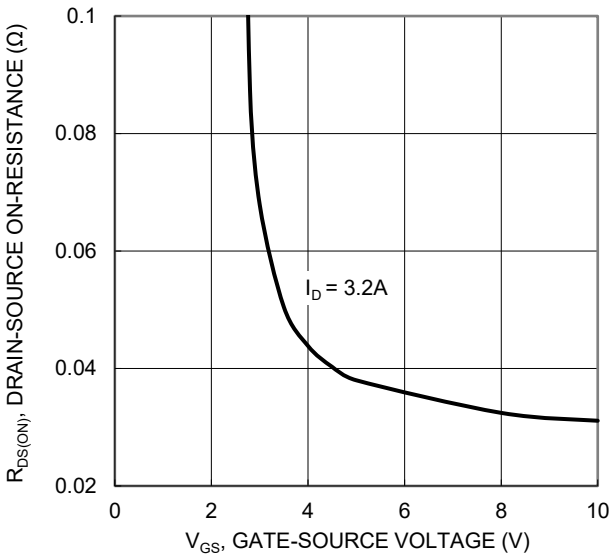


Figure 4. Typical Transfer Characteristic

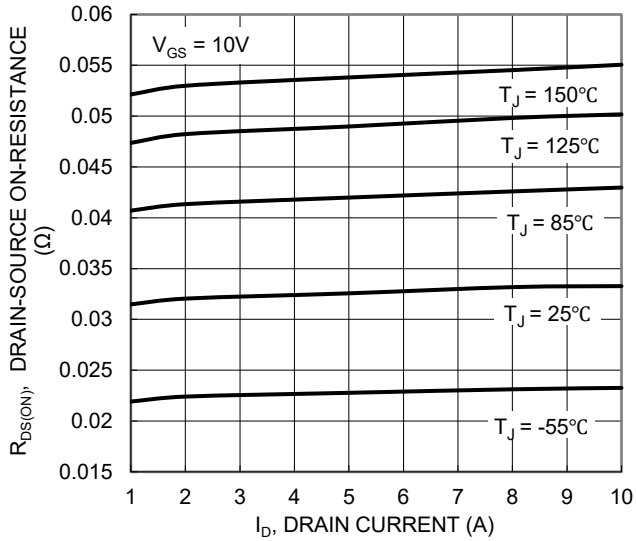


Figure 5. Typical On-Resistance vs. Drain Current and Junction Temperature

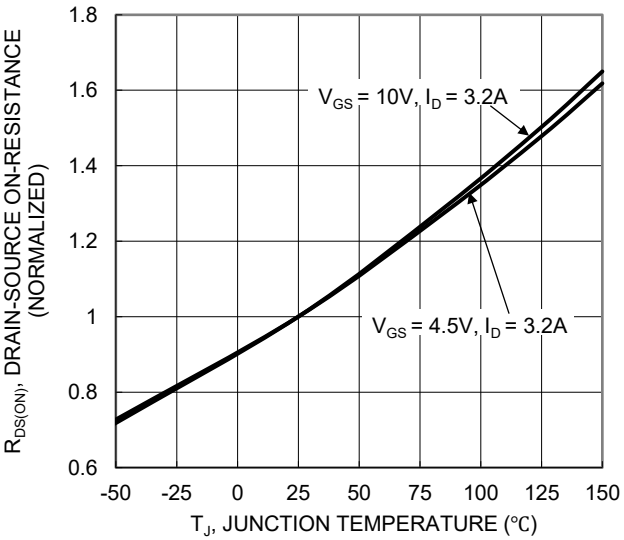


Figure 6. On-Resistance Variation with Junction Temperature

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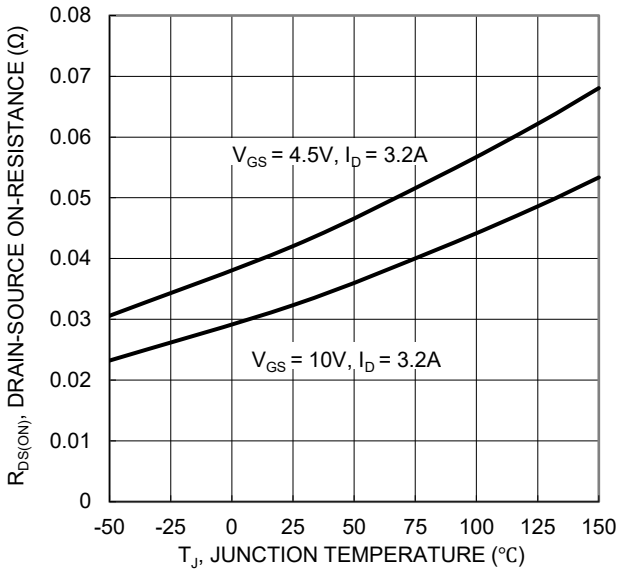


Figure 7. On-Resistance Variation with Junction Temperature

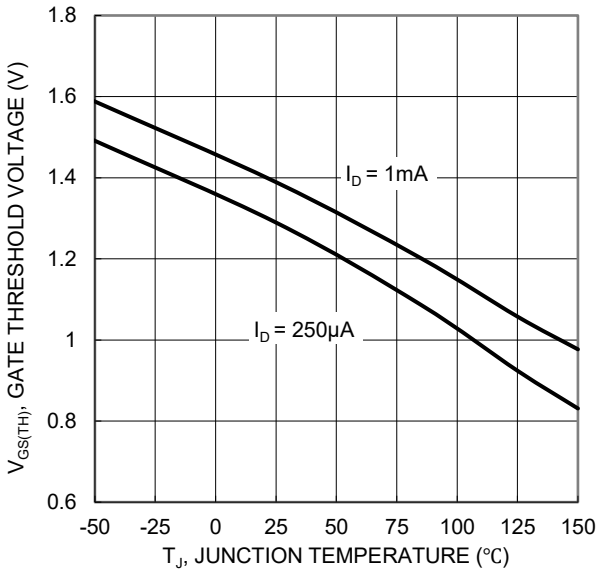


Figure 8. Gate Threshold Variation vs. Junction Temperature

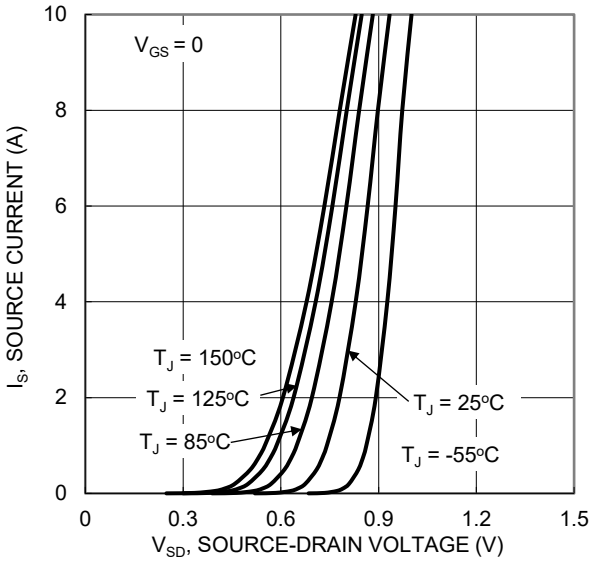


Figure 9. Diode Forward Voltage vs. Current

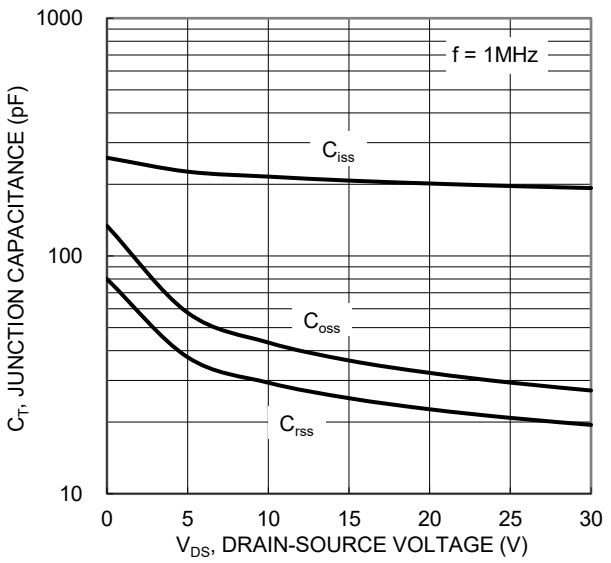


Figure 10. Typical Junction Capacitance

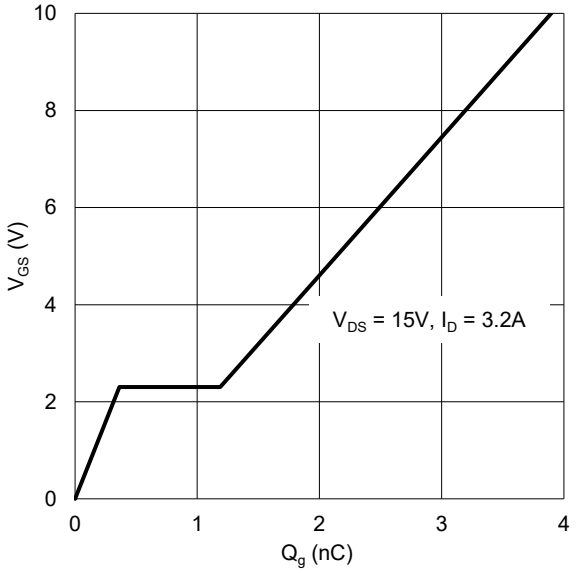


Figure 11. Gate Charge

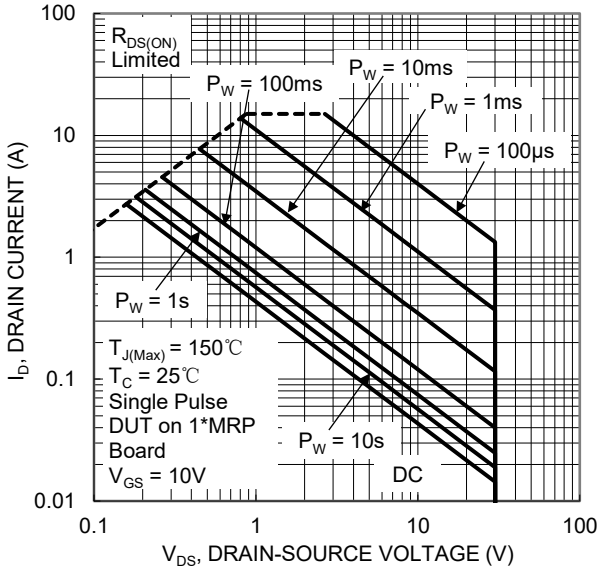


Figure 12. SOA, Safe Operation Area

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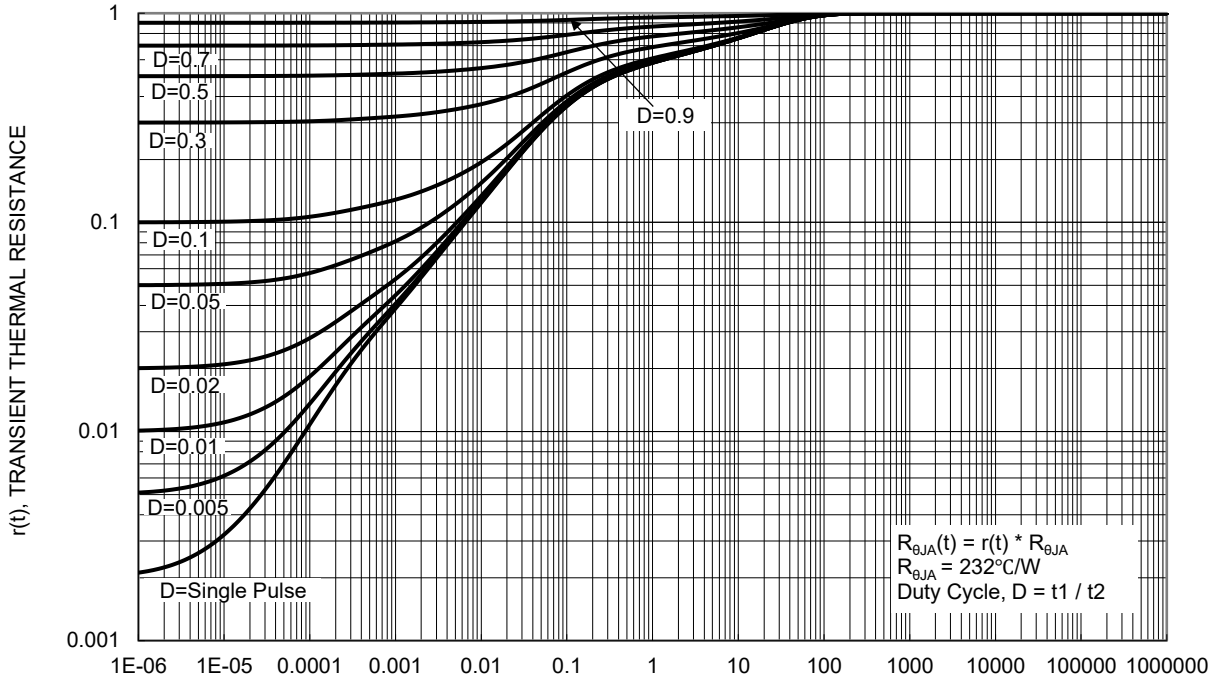


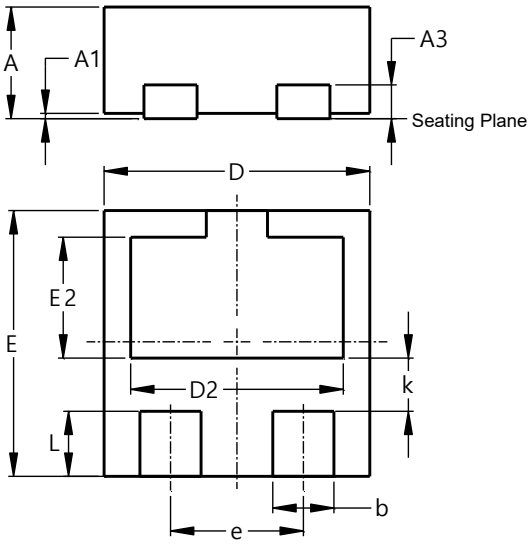
Figure 13. Transient Thermal Resistance

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Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

X2-DFN1010-3

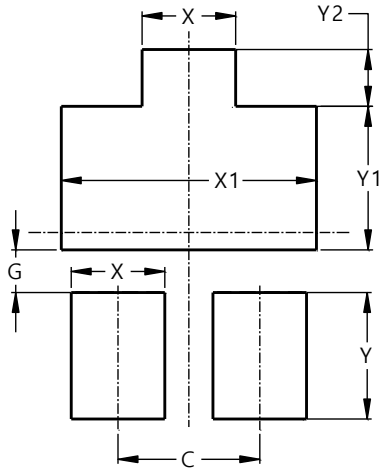


X2-DFN1010-3			
Dim	**Min**	**Max**	**Typ**
A	-	0.40	0.39
A1	0.00	0.05	0.02
A3	-	-	0.13
b	0.18	0.28	0.23
D	0.95	1.05	1.00
D2	0.70	0.90	0.80
E	0.95	1.05	1.00
E2	0.36	0.56	0.46
e	-	-	0.50
k	-	-	0.20
L	0.195	0.295	0.245
All Dimensions in mm			

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

X2-DFN1010-3



Dimensions	Value (in mm)
C	0.500
G	0.150
X	0.330
X1	0.900
Y	0.445
Y1	0.505
Y2	0.200

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